

# **CML Semiconductor Products**

PRODUCT INFORMATION

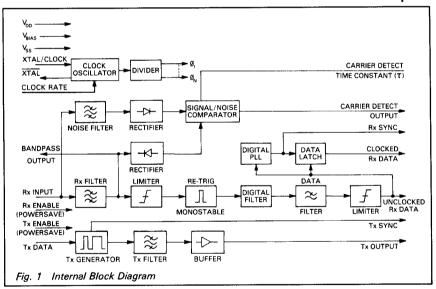
# FX439 FFSK Modem

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#### Features/Applications

- 1200 Baud FFSK Modem
- Meets Cellular and Trunked Radio Specifications
- Full-Duplex 1200 Baud
- On-Chip Rx and Tx Bandpass Filters
- Clock Recovery and Carrier Detect Facilities
- Pin Selectable Xtal/Clock Frequencies (1.008MHz or 4.032MHz Input)

- Mobile and Cellular Radio Data Signalling
- NMT 450/900
- Band III
- Radiocom 2000
- ZVEI
- Personal Radio
- Portable Data Terminals
- General Purpose Applications



**FX439** 

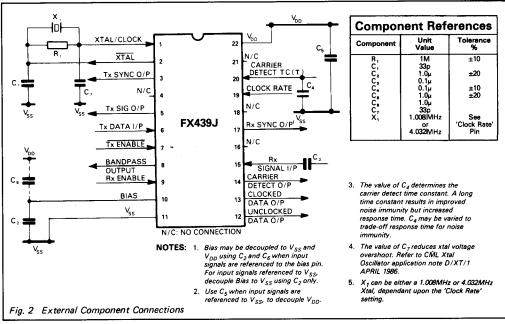
## **Brief Description**

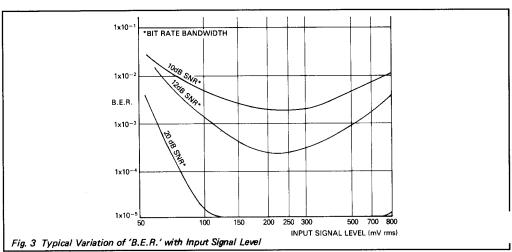
The FX439 is a single-chip CMOS LSI circuit which operates as a 1200 baud FFSK modem. The mark and space frequencies are 1200Hz and 1800Hz phase continuous and the frequency transitions occur at the zero crossing point. The transmitter and receiver will work independently, thus providing full-duplex operation at 1200 baud. The baud rate, transmit mark and space frequencies, Tx and Rx synchronization are all derived from a highly stable Xtal oscillator. The onchip oscillator is capable of working at one of two input frequencies, from a 1.008MHz or

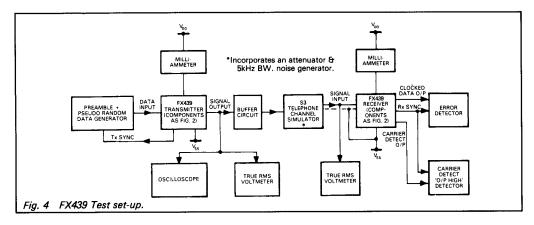
4.032MHz external Xtal/clock input, frequency being pin selectable with the 'Clock Rate' logic input. The device includes circuitry for carrier detect and facility for the Rx clock recovery. An on-board switched capacitor 900Hz — 2100Hz bandpass filter provides optimum carrier filtering. The use of switched capacitor analogue filters and digital signal processing results in excellent dynamic performance with few external components, the CMOS process and current saving techniques offer low standby supply current for portable battery powered applications.

Pin Number			Function					
FX439 DW	FX439 J	FX439 LG/LS						
1	1	1	Xtal/Clock: The input to the on-chip inverter, for use with either a 1.008MHz or a 4.032MHz Xtal or external clock. Clock frequency selection is by the "Clock Rate" input pin.					
2	2	2	Xtal: Output of the on-chip inverter (See Figure 2).					
3	3	3	Tx Sync O/P: A 1200Hz squarewave used to synchronize the input of logic data and transmission of the FFSK signal (See Figure 5).					
4	5	5	Tx Signal O/P: When the transmitter is enabled, this pin outputs the 1200/1800Hz (140-step pseudo sinewave) FFSK signal (See Figure 5). With the transmitter disabled, this output is set to a high-impedance state.					
5	6	7	Tx Data I/P: Serial logic data to be transmitted is input to this pin.					
6	7	8	Tx Enable: A logic '0' will enable the transmitter (See Figure 5). A logic '1' at this input will put the transmitter into powersave whilst forcing the "Tx Sync O/P" to a logic '1' and "Tx Signal O/P" to a high-impedance state. This pin is internally pulled to V <sub>DO</sub> .					
	8	9	Bandpass O/P: The output of the Rx 900Hz-2100Hz bandpass filter. This output impedance is typically $10k\Omega$ and may require buffering prior to use.					
8	9	10	Rx Enable: The control of the Rx function. The control of other outputs is given below.					
		Ī	Rx Enable = Rx Function Clock Data O/P Carrier Detect Rx Sync Out					
		- 1	"1" = Enabled Enabled Enabled Enabled					
		1	"0" = Powersave "0" "0" 1" or "0"					
			When both Tx and Rx functions are disabled, the bias voltage is switched internally to V (via $\approx\!25\mathrm{k}\Omega$ ). Bias line $R_{\mathrm{O,IT}}\approx\!12.5\mathrm{k}\Omega$ . With the Bias line decoupled by a $1.0\mu\mathrm{F}$ capacitor ( $C_2^{\mathrm{S}}$ ) the FX439 may take approximately 25 milli-seconds to establish correct operation when enabling the Rx facility. This period may be minimized by either: reducing the value of $C_2$ , lowering the bias line impedance externally or adopting a different powersaving strategy (such as using $C_2$ and $C_6$ and supplying $V_{\mathrm{DD}}$ via a series switch). This pin is internally pulled to $V_{\mathrm{DD}}$ .					
9	10	11	<b>Blas:</b> The output of the on-chip analogue bias circuitry. Held internally at $V_{\rm DD}/2$ , this pin should be decoupled to $V_{\rm SS}$ by a capacitor ( $C_2$ ). (See Figure 2 and $Rx$ Enable notes).					
10	11	12	V <sub>ss</sub> : Negative supply rail (GND).					
11	12	13	Unclocked Data O/P: The recovered asynchronous serial data output from the receiver.					
12	13	14	Clocked Data O/P: The recovered synchronous serial data output from the receiver. Data is latched out by the recovered clock, available at the "Rx Sync O/P," (See Figure 6).					
13	14	15	Carrier Detect O/P: When an FFSK signal is being received this output is a logic '1.'					
	15	16	Rx Signal I/P: The FFSK signal input for the receiver. This input should be coupled via a capacitor, C <sub>3</sub> .					
15	17	18	Rx Sync O/P: A flywheel 1200Hz squarewave output. This clock will synchronize to incoming Rx FFSK data (See Figure 6).					
18	19	21	Clock Rate: A logic input to select and allow the use of either a 1.008MHz or 4.032MHz Xtal/clock. Logic '1' = 4.032MHz, logic '0' = 1.008MHz. This input has an internal pulldown resistor (1.008MHz).					
19	20	22	Carrier Detect Time Constant ( $\tau$ ): Part of the carrier detect integration function. The value of C <sub>4</sub> connected to this pin will affect the carrier detect response time and hence noise performance (Ser Figure 2, Note 3).					
20	22	24	V <sub>po</sub> : Positive supply rail. A single 5-volt supply is required.					
16,	4,	4, 6, 17,19, 20, 23	No Internal Connection, do not use.					
17	16,18, 21		Note: Output Loading. Large capacitive loads would cause the output pins of this device to oscillate. If capacitive loads in excess of 200pF are unavoidable, a resistor of typically 100Ω put in series with the load should minimise this effect.					

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#### **Specification**

### **Absolute Maximum Ratings**

Exceeding the maximum rating can result in device damage. Operation of the device outside the operating limits is not implied.

Supply voltage Input voltage at any pin (ref  $V_{SS} = OV$ ) Output sink/source current (total) Operating temperature range: FX439J FX439DW/LG/LS Storage temperature range: FX439J

FX439DW/LG/LS

Total device dissipation @ T<sub>AMB</sub> 25°C Derating

20mA -30°C to +85°C (cerdip) -30°C to +70°C (plastic)

-0.3V to  $(V_{DD} + 0.3V)$ 

-0.3V to 7.0V

-55°C to +125°C (cerdip) -40°C to +85°C (plastic)

800mW Max. 10mW/°C

#### **Operating Limits**

All characteristics measured using the standard test circuit (Figure 4) with the following test parameters and is valid for all tests unless otherwise stated:

 $V_{DD} = +5V$ ,  $T_{amb} = 25^{\circ}C$ , Xtal (X<sub>1</sub>) Frequency: 1.008MHz

0dB reference Noise

SNR ratio measured in bit rate bandwidth (1200Hz)

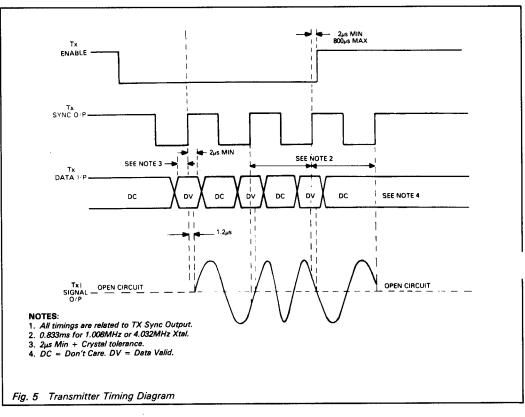
300mV rms

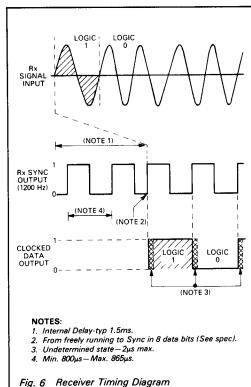
(band limited 5kHz gaussian white noise)

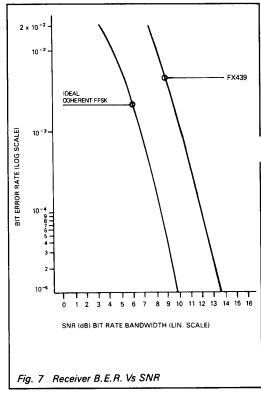
Static Characteristics Supply Volts Supply Current: Rx (Enabled) Tx (Disabled) Rx (Enabled) Tx (Enabled) Rx (Disabled) Tx (Disabled) Logic '1' level Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: Rin Rout Inverter Gain Gain Bandwidth Product Crystal Frequency	4.5   80%V <sub>DD</sub>  100  10 5 10 3 x 10 <sup>6</sup>	5.0 3.6 4.5 650  4 10	5.5    20%V <sub>DD</sub>  	V mA mA μA V V kΩ kΩ
Supply Current: Rx (Enabled) Tx (Disabled) Rx (Enabled) Tx (Enabled) Rx (Disabled) Tx (Disabled) Logic '1' level Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: R in R out Inverter Gain Gain Bandwidth Product	  80%V <sub>DD</sub>  100  10 5	3.6 4.5 650 — 4	   20%V <sub>DD</sub>  	mA mA μA V kΩ kΩ
Rx (Enabled) Tx (Enabled) Rx (Disabled) Tx (Disabled) Logic '1' level Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: R in R out Inverter Gain Gain Bandwidth Product	  80%V <sub>DD</sub>  100  10 5	3.6 4.5 650 — 4	   20%V <sub>DD</sub>  	mA mA μA V kΩ kΩ
Rx (Enabled) Tx (Enabled) Rx (Disabled) Tx (Disabled) Logic '1' level Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: R in R out Inverter Gain Gain Bandwidth Product	- 100 - 10 5 10	4.5 650 — — 4 —	  	mΑ μΑ V kΩ kΩ
Rx (Disabled) Tx (Disabled) Logic '1' level Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: Rin Rout Inverter Gain Gain Bandwidth Product	- 100 - 10 5 10	650   4 	  	μΑ V V kΩ kΩ
Logic '1' level Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: Rin Rout Inverter Gain Gain Bandwidth Product	- 100 - 10 5 10	4	  	V V kΩ kΩ kΩ
Logic '0' level Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: Rin Rout Inverter Gain Gain Bandwidth Product	- 100 - 10 5 10	- 4 -	  	V kΩ kΩ kΩ
Digital Output Impedance Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: Rin Rout Inverter Gain Gain Bandwidth Product	10 5 10	<b>4</b> —	  	kΩ kΩ kΩ
Analogue and Digital Input Impedance Tx Output Impedance On-Chip Crystal Oscillator: Rin Rout Inverter Gain Gain Bandwidth Product	10 5 10	<u>-</u>		kΩ kΩ
Tx Output Impedance On-Chip Crystal Oscillator: R <sub>in</sub> R <sub>out</sub> Inverter Gain Gain Bandwidth Product	10 5 10	10 - -		kΩ
On-Chip Crystal Oscillator: R <sub>in</sub> R <sub>out</sub> Inverter Gain Gain Bandwidth Product	5 10	 	-	
R <sub>in</sub> R <sub>out</sub> Inverter Gain Gain Bandwidth Product	5 10	_	_	
R <sub>out</sub> Inverter Gain Gain Bandwidth Product	5 10		_	
Inverter Gain Gain Bandwidth Product	10	· <del>-</del>		$M\Omega$
Gain Bandwidth Product			15	kΩ
	3 x 10°	_	20	dB
Crystal Frequency			_	
	_	1.008	_	MHz
		4.032		MHz
ynamic Characteristics Receiver:				
Signal Input: Dynamic Range (50dB SNR) 2, 3	100	230	1000	mV rm
Bit Error Rate: 12dB SNR 3	_	7.0		10-4
20dB SNR 3		1.0	_	10-8
eceiver Synchronization 12dB SNR: 6				
Probability of Bit 8 being correct		0.99		
Probability of Bit 16 being correct		0.995		
arrier Detect 4				
Sensitivity 6, 7	_	_	150	mV rms
Probability of Carrier Detect being high:				
12dB SNR after Bit 8 4, 8	_	0.98		
12dB SNR after Bit 16 4, 8		0.995	****	
0dB Noise (No Signal) 8	_	0.05	_	
ransmitter Output		0.00		
Tx Output Level	-	775	_	mV rms
Output Level Variation 1200/1800Hz	0	-	±1.00	dB
Output Distortion	_	3	5	%
3rd Harmonic Distortion	_	2	3	% %
Logic '1' Carrier Frequency 5	_	1200	J	∞ Hz
Logic '0' Carrier Frequency 5	_	1800	_	
Isochronous Distortion	<del></del>	1000	_	Hz
1200Hz – 1800Hz		25	40	
1800Hz – 1200Hz		25 20	40 40	μs μs

- Notes: 1. Crystal frequency, type and tolerance depends on system requirements.
  - 2. See Figure 3. 4. See Figure 2 Note 3.
    - 3. SNR (Bit Rate Bandwidth).

- 6. 10101010101 . . . pattern.
- 5. Depending on crystal tolerance. 7. Measured with 150mV rms signal (No noise).
- 8. OdB level for CD probability measurements is 230mV rms.







## **Package Outlines**

The FX439DW, the S.O.I.C. package is shown in Figure 8, the 'J' version in Figure 9, the 'LG' version in Figure 10 and the 'LS' version in Figure 11.

Pin 1 identification marking is shown on the relevant diagram and pins on all package styles number anticlockwise when viewed from the top (indent side).

Fig.8 FX439DW S.O.I.C. Package

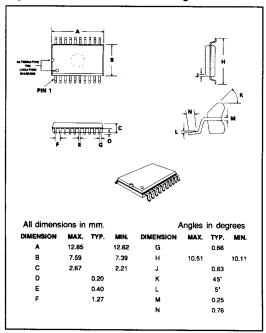
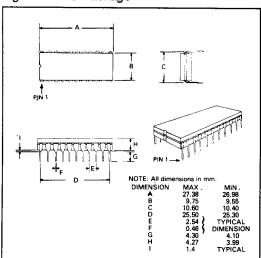


Fig.9 FX439J Package



# **Handling Precautions**

The FX439 is a CMOS LSI circuit which includes input protection. However precautions should be taken to prevent static discharges which may cause damage.

Fig.10 FX439LG Package

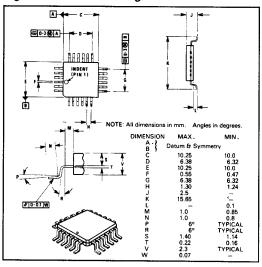
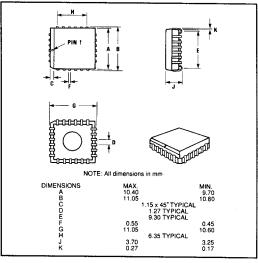


Fig.11 FX439LS Package



# **Ordering Information**

FX439DW	20-pin surface mount S.O.I.C
FX439J	22-pin cerdip DIL
FX439LG	24-pin quad plastic encapsulated, bent and cropped
FX439LS	24-lead plastic

leaded chip carrier